LIST 13 (See S.No.184 of the Table)

- (1) LSI / VLSI tester
- (2) Micromanipulators
- (3) Molecular beam expitaxy system (MBE system)
- (4) Expitaxial reactors
- (5) Chemical vapour deposition (CVD) system Low pressure CVD (LP CVD) Metal organic CVD (MO CVD)
- (6) High pressure oxidation systems
- (7) Chemical etching systems
- (8) Plasma etchers
- (9) Reactive ion beam etchers (RIBE)
- (10) Reactive ion etchers
- (11) RF sputtering systems
- (12) Direct digital control furnaces
- (13) Ion-implanters (low/ medium / high current)

- (14) Lithography systems
- (15) Direct step on wafers / steppers
- (16) X-ray lithography systems
- (17) E-Beam mask making system
- (18) E-Beam direct write system
- (19) Mask aligners
- (20) Mask inspection systems (comparators)
- (21) Tape automated bounders
- (22) Laser zappers
- (23) Wafer recognition wire bonders
- (24) Wafer scriber or Wafer slicer or Wafer sawing machine or Wafer fractures or any combination thereof
- (25) Die bonders or wire bonders or combination thereof

- (26) Wafer sawing machine; Wafer prober
- (27) Leak detection system
- (28) Clean room air showers
- (29) Particle monitor / counter both air and liquid borne
- (30) Automatic encapsulation system; Automatic marking / branding machine
- (31) Clean room laminar flow air handling system
- (32) Ultra clean room equipment
- (33) Ultra high purity demineralised water treatment plant
- (34) PVDF welding and orbital welding machines
- (35) Ultra high pure (UHP) gas distribution system
- (36) Toxic gas distribution / monitoring system